

Silicon Double Balanced HMIC Mixer 850 – 1050 MHz

Rev. V2

#### **Features**

- + 21 dBm Typical Input IP3
- 8. 3 dB Typical Conversion Loss
- + 5 to + 10 dBm LO Drive
- Fully Balanced Passive Mixer
- NO External Matching Required
- Low Cost Miniature Plastic MLP Package

#### **Description**

M/A-COM's MA4EXP950L-1277 is a silicon monolithic 850-1050 MHz , low barrier, double balanced mixer in a low cost, miniature surface mount FQFP-N 3mm Square, 16 lead plastic package. The die uses M/A-COM's unique HMIC silicon/glass process to realize low loss passive elements while retaining the advantages of low barrier silicon schottky barrier diodes to produce a compact device.

### **Applications**

These mixers are well suited for GSM and CDMA Cellular basestation applications where small size and high performance are required. Typical applications include frequency conversion, modulation, and demodulation in wireless receivers and transmitters.

#### MLP 3mm Package - Circuit Side View



PIN 1 PIN 16

#### **PIN CONFIGURATION (Center Area is Ground)**

PIN	Function	PIN	Function	
1	N/C	9	N/C	
2	N/C	10	RF	
3	LO	11	N/C	
4	N/C	12	N/C	
5	N/C	13	N/C	
6	N/C	14	IF	
7	N/C	15	N/C	
8	N/C	16	N/C	

**Ordering Information** 

Model No.	Package		
MA4EXP950L-1277T	Tape and Reel		

### Electrical Specifications @ +25°C

Parameter	Frequency Range	Test Conditions	Units	Min.	Тур.	Max.
Conversion Loss	900 MHz	LO Drive = +7 dBm	dB	-	8.2	8.9
	850-1050 MHz	RF = -10  dBm, IF = 60  MHz		-	8.5	9.5
L - R Isolation	900 MHz	LO Drive = +7 dBm	dB	-	65	-
	850-1050 MHz	RF Level = - 10 dBm		-	62	-
L - I Isolation	900 MHz	LO Drive = +7 dBm	dB	-	46	-
	850-1050 MHz	RF Level = - 10 dBm		-	46	-
R - I Isolation	900 MHz	LO Drive = +7 dBm	dB	-	23	-
	850-1050 MHz	RF Level = - 10 dBm		-	23	•
LO VSWR	900 MHz	LO Drive = +7 dBm	Ratio	-	1.5:1	-
	850-1050 MHz	RF Level = - 10 dBm		-	1.5:1	•
RF VSWR	900 MHz	LO Drive = +7 dBm	Ratio	-	1.3:1	
	850-1050 MHz	RF Level = - 10 dBm		-	1.5:1	-
IF VSWR	DC - 400 MHz	LO Drive = +7 dBm	Ratio	-	1.5:1	-
		IF Level = - 10 dBm				
Input IP3	900 MHz	LO Drive = +7 dBm	dBm	17.8	21.0	-
	850-1050 MHz	RF = - 10 dBm, IF = 60 MHz		16.9	20.5	-
Input 1dB Compression	850-1050 MHz	LO Drive = +7 dBm,IF = 60 MHz	dBm	-	4.3	-
IF 1 dB Bandwidth	DC - 400 MHz	LO =900 MHz @ +7dBm	MHz	0	-	400

India Tel: +91.80.43537383
China Tel: +86.21.2407.1588
Visit www.macomtech.com for additional data sheets and product information.

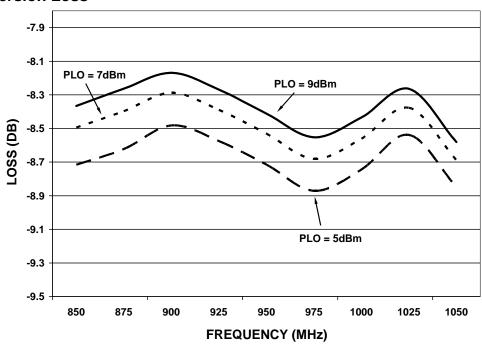


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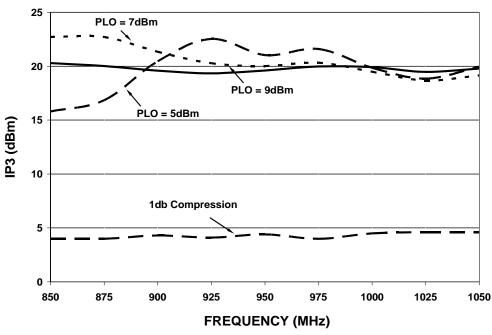
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#### Typical Performance Curves (LO Drive= +5, +7, +9 dbm, RF= -10dBm, IF= 60MHz)

#### **Conversion Loss**



#### Input IP3 and P1dB



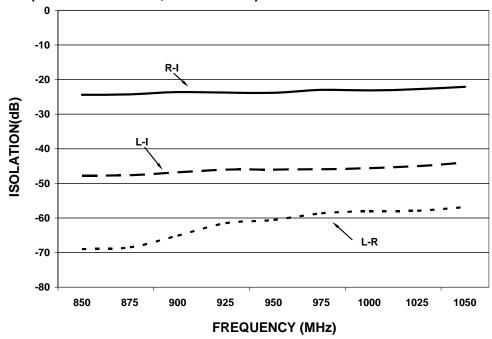
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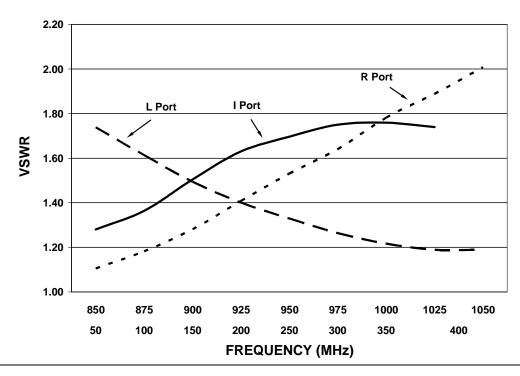
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#### Isolation (LO Drive= +7dbm, RF= -10dBm)



#### VSWR (LO Drive= +7dbm, RF= -10dBm, IF=-10dBm)

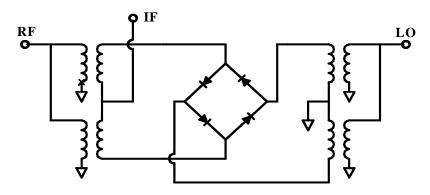




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#### **Mixer Schematic**



Absolute Maximum Ratings<sup>1</sup>

Absolute Maximum Natings				
Parameter	Maximum Ratings			
Operating Temperature	-40°C to +85°C			
Storage Temperature	-65°C to +150°C			
Incident LO Power	+20 dBm C.W.			
Incident RF Power	+20 dBm C.W.			

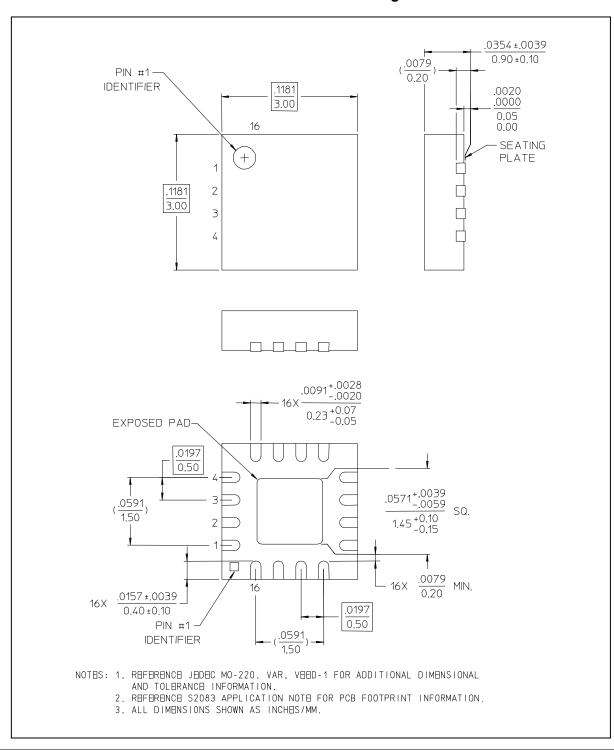
<sup>1.</sup> Exceeding these limits may cause permanent damage.



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#### MA4EXP190H-1277 Outline - 3mm FQFP-N 16 Lead Saw Singulated



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